Formation and Properties of a Bicyclic Silylated Digermene


In memory of Michael Bendikov

Abstract: In the presence of PMe3 or N-heterocyclic carbenes, the reaction of oligosilanylene dianions with GeCl2·dioxane gives germylene–base adducts. After base abstraction, the free germynes can dimerize by formation of a digermene. An electrochemical and theoretical study of a bicyclic tetrasisylated digermene revealed formation of a comparably stable radical anion and a more reactive radical cation, which were characterized further by UV/Vis and ESR spectroscopy.

Introduction

In recent years, the chemistry of the heavier carbene[1–5] and alkene[6–14] analogues has become an intensely studied field. Although much of the research in this particular area concentrates on the elements silicon and tin, germanium is also becoming increasingly popular. A simple way of classifying these compounds is according to substituent types. Starting with Lappert’s seminal work, π-basic (donating) substituents such as N(SiMe3)2[18] or more recently SR,[19] have been recognized as suitable ligands for tetrylenes, which are stabilized by way of π donation into the empty p orbital. One consequence of this stability is a diminished tendency to dimerize to heavy alkene analogues.

Alkyl, aryl, or silyl substituted tetrylenes on the other hand are much more reactive and exhibit a pronounced tendency for dimerization or even oligomerization. The fact that linear or cyclic chains of heavy Group 14 atoms are formally composed of tetrylenes can be utilized to access these species for instance by photochemical methods. In cases with sterically demanding substituents, tetrylenes typically dimerize to heavy alkene analogues.

Reactions of organometallic reagents with divalent heavy Group 14 halides can be considered as an interesting synthetic alternative to tetrylenes and, after dimerization, to heavy alkene formation. A major reason why this strategy is only a rarely employed route may be the incompatibility of free tetrylenes and the strongly nucleophilic organometallic reagents.

Recently, we described the reaction of a 1,4-dipotassiotetrasilane with GeBr2·dioxane and PEt3 to give the phosphane adduct of a germylene embedded into a five-membered cyclosilane ring.[20] The presence of the phosphane as a donor molecule prevents further interaction of the germylene with the potassium silanide. The release of the free germylene can be accomplished by base abstraction with the strong Lewis acid B(C6F5)3. For the case of the five-membered germylene, this resulted in a subsequent 1,2-trimethylsilyl shift to form a silagermene, which eventually dimerized in a [2+2]-cycloadition reaction.[20]

Herein, we describe the synthesis of related germylene–base adducts which upon being released, dimerize and rearrange to oligocyclic silylated digermenes. The reasons for the fundamentally different reactivity of the two cyclic silylgermylenes can be explained on the basis of theoretical calculations. One digermene was investigated with respect to its redox properties by spectroelectrochemical and theoretical methods.
Results and Discussion

Formation

The reaction of the 1,3-dipotassiotsilane 1 with GeBr₂·dioxane and PEt₃ was found to give not the respective germylene base adduct but rather a bicyclic digermene 2 (Scheme 1), in close analogy to what had been observed before by Kira and co-workers for a related disilylated silylene.[22, 23] Change of PEt₃ for PMe₃ in the reaction again led to digermene 2, but in this case, the PMe₃ adduct 3 of the transient germylene 4 was detected in solution by NMR spectroscopy. Upon removing the solvent in vacuum, 2 formed again.

The use of tetramethylimidazol-2-ylidene (IMe₄) as a base allowed the selective formation of NHC-stabilized germylene 5 (Scheme 1).[24]

The difference between the dimerization reactivity of the four-membered cyclic germylene 4 and the previously disclosed reactivity of its direct homologue, the five-membered cyclic germylene 6,[20] is striking. Common to both germyles 4 and 6 is their tendency to form zwitterionic complexes with phosphanes. The complex between germylene 6 and PMe₃ 7 is stable at room temperature and an isolable compound (Scheme 2).[20] Without stabilization by an additional Lewis base, however, germylene 6 underwent a 1,2-silyl shift to give cyclic silagemene 17, which dimerizes to give the tricyclic polysiladigermane 18 (Scheme 2).[20]

In contrast, the PMe₃ complex of the four-membered cyclic germylene (3), is not stable at temperatures as low as −20 °C. At this temperature, germylene 4 dimerizes to give, after skeletal rearrangement, bicyclic digermene 2 (Scheme 1 and 2). We used density functional calculations[25] to provide some understanding of this surprising difference between the reactivity of four-membered cyclic germylene 4 and that of its five-membered homologue, 6.

A possible rearrangement of germylene 4 to the cyclic silagemene 10 is only slightly endergonic and is connected with a free-energy barrier at T = 253 K of 63 kJ mol⁻¹. In this respect, a comparison with homologous germylene 6 reveals no fundamental difference (see Figure 1). The calculated bond dissociation energy (BDE) of the Ge–P bond of PMe3 adduct 3 is how-

![Scheme 1. Reactions of 1,3-trisilanylene dianion 1 with GeBr₂·dioxane in the presence of bases.](image)

![Scheme 2. Comparison of the different reactivities of germylene–phosphane complexes 3 and 7[20] (Si = SiMe₃).](image)

![Figure 1. Relative free Gibbs enthalpies at 253 K for germylene 4, silagemene 10, and digermene 2 and its isomers 11, 12, as calculated at M062X/6-311 + G(d,p)(Si, C, H) def2-tzp (Ge) (in black, Si = SiMe₃). For comparison, literature data[24] for the homologous compounds 6 and 14–17 are also shown (at 298 K, in gray).](image)
ever reduced compared to that of related phosphate adduct 7, in agreement with the observed lower temperature stability of 3, BDE(Ge–P) = 113 kJ mol⁻¹ (3) versus 130 kJ mol⁻¹ (7).[20] The increased thermal instability of adduct 3 delivers germylene 4 at temperatures as low as −20 °C. At these temperatures, the silylgemylene/silagermene rearrangement to give silagermene 10 (Figure 1) is relatively slow.[26] This favors the competing practically barrier free dimerization of germylene 4 to give digermene 11 (Scheme 2, Figure 1).

After double silyl migration via germylgemylene 12, the thermodynamically most stable compound in this series, digermene 2, is obtained (see Figure 1). The results of the calculations indicate that dimerization of germylene 4 to digermene 11 has a strong thermodynamic driving force as it is favored by ΔE°ST = −121 kJ mol⁻¹. In contrast, the corresponding dimerization of germylene 6 is practically thermoneutral (ΔE°ST = −6 kJ mol⁻¹, see Figure 1).[20] One reason for this difference might be the electronic structure of the germynes and, as a consequence, the structures and stabilities of the respective dimers. Substitution with electropositive silyl groups leads to a smaller energy separation between the singlet and triplet states of the gemylene, ΔES(T)[10] in agreement with established theoretical models.[27–29] almost planar tetrasilyldigermenes with relative short Ge–Ge bonds (Ge–Ge = 226.7–229.8 pm) are formed upon their dimerization.[30] The acute Si–Ge–Si bond angle of four-membered cyclic germylene 4 increases ΔES(T) for this germylene compared to that of five-membered cyclic gemylene 6 or to related acyclic germynes ((Me₅Si)₂Ge; Ge: 13 (4): α(Si–Ge–Si): 80.6°, ΔES(T) = 102 kJ mol⁻¹; 6: α(Si–Ge–Si): 93.6°, ΔES(T) = 86 kJ mol⁻¹; 13: α(Si–Ge–Si) = 112.1, ΔES(T) = 71 kJ mol⁻¹).

The higher ΔES(T) for germylene 4 results in a molecular structure of Ge–Ge-bonded dimer 11 that has a significant trans–bent arrangement (Figure 2).[31] This trans–bent conformation efficiently separates the bulky silyl substituents at the two different germanium atoms of 11 and stabilizes germylene dimer 11 relative to its constituent monomers. In contrast, the smaller ΔES(T) of germylene 6 induces only a small trans-bending of digermene 14 (Figure 2) and, consequently, the Ge–Ge bond is weakened by the steric repulsion of the neighboring silyl groups. A structural indication for this scenario is provided by the fact that the trans–bent distorted Ge–Ge bond of digermene 11 is shorter than the almost-planar Ge–Ge bond of digermene 14, a reversal of the expected and previously documented trend.[13]

The reaction of 1,4-dipotassiocyclohexasilane 19[33] with GeBr₂·dioxane and PEt₃ proceeded in a similar way, but germylene–phosphane adduct 20 (Scheme 3) was found to be slightly more stable than 3 and was characterized by multinuclear NMR spectroscopy. Attempts to crystallize the compound eventually led to the isolation of tetracyclic digermene 21. The same reaction in the presence of carbene IMe₄ gave stable NHC–gemylene adduct 22 (Scheme 3).

Crystallography

Compounds 2, 21, and 22 were subjected to single-crystal structure analysis. As expected, the digermene 2 (Figure 3) is...
isostructural to the disilene previously reported by Kira and co-workers.\textsuperscript{30} The Ge–Ge double bond of 2.2663(9) Å is slightly shorter than other tetrasilylated digermenes reported so far.\textsuperscript{30, 34} Also the Si–Ge bonds of 2.371(2) and 2.366(1) Å are unusually short and in the same range as the Si–Si bonds in the molecule. While 2 has a very small trans–bent angle of 2.5° the twisting angle between the disilylated germylene units, τ, is 16.2°.

For related digermene 21 (Figure 4), which is sterically more crowded, all bonds are slightly elongated compared to 2. This is shown by a Ge–Ge double bond length of 2.2896(6) Å and by Si–Ge bonds ranging from 2.3836(6) to 2.3914(8) Å, which are still unusually short. The Si–Si distances cover a rather typical range from 2.339 to 2.356 Å. The diminished twisting angle between the germylene units, τ, of 5.2° and the trans–bent angles of 8.3° and 2.1° indicate that the digermene unit of 21 is almost planar. Twisting and trans–bent angles of 2 and 21 are in accordance to Kira’s tetrasilylated digermenes.\textsuperscript{30, 34}

Bicyclic NHC–germylene adduct 22 (Figure 5) very much resembles the previously published NHC adduct of the monocyclic five-membered disilylated germylene.\textsuperscript{20} The Ge–C distance of 2.055(2) Å and the Ge–Si distances of 2.4817(7) and 2.4861(7) Å are almost identical to the respective values of the previously published adduct, 2.071(3), 2.4709(9), and 2.4795(9) Å.\textsuperscript{20} The same is true for the angles between the Si–Ge–Si plane and the Ge–NHC bond, which is close to 105° for 22 and about 105° for the five-membered ring.

**NMR spectroscopy**

The NMR spectroscopic comparison of compounds 2, 3, and 5 with 20, 21, and 22 is interesting as these correspond to two sets of disilylated germylene adducts with different oligosilylene backbones. The most informative nucleus to discuss with respect to this is of course $^2$Si (Table 1). The resonances for 2 are observed at $-9.7$ (SiMe$_3$), $-10.5$ (SiMe$_2$), and $-92.7$ (SiH) ppm, with the SiMe$_3$ and SiMe$_2$ resonances being almost identical to Kira’s analogous silylene (−8.7, −11.4, −107.1 ppm).\textsuperscript{30} Digermene 21 shares with 2 the downfield-shifted resonances for the quaternary silicon atoms, which are attached to the double-bonded germanium atoms.

Compounds 3, 5, 20, and 22 are all germylene adducts with either PMe$_3$ (3, 20) or IMe$_3$ (5, 22) as the base. The $^2$Si resonances of 20 and 22, which share the bicyclo[2.2.1] backbone, are very similar (Table 1). Chemical shifts around $-6$ ppm are typical for bridgehead-connected SiMe$_3$ groups. The fact that for 20 and 22 two resonances were observed for the SiMe$_3$ groups indicates configurational stability of the germylene atoms. On the other hand, there is a difference between compounds 3 and 5 in that respect. For 3 at ambient temperature, only one resonance for the SiMe$_3$ groups was observed, whereas for 5, at the same temperature, no SiMe$_3$ resonance was observed for reasons of coalescence and only at 60 °C a sharp signal was detected. This result clearly indicates a lack of configurational stability of the germanium atom at room tempera-

![Figure 4. Crystal structure of 21. Thermal ellipsoids are represented at the 30% level and hydrogen atoms have been omitted for clarity. Ge(1)-Ge(2) 2.2897(6), Ge(1)-Si(12) 2.3836(8), Ge(1)-Si(1) 2.3902(9), Ge(2)-Si(4) 2.3838(8), Ge(2)-Si(9) 2.3913(9), Si(1)-Si(2) 2.3415(9), Ge(2)-Ge(1)-Si(12) 111.563(19), Ge(2)-Ge(1)-Si(1) 113.000(17), Si(12)-Ge(1)-Si(1) 134.93(3), Ge(1)-Ge(2)-Si(4) 111.915(19), Ge(1)-Ge(2)-Si(9) 112.613(17), Si(4)-Ge(2)-Si(9) 135.44(3).](image1)

![Figure 5. Crystal structure of 22. Thermal ellipsoids are represented at the 30% level and hydrogen atoms have been omitted for clarity. Ge(1)-C(1) 2.055(2), Ge(1)-Si(4) 2.4817(7), Ge(1)-Si(1) 2.4861(7), N(1)-C(1) 1.343(3), N(2)-C(1) 1.361(3), Si(1)-Si(2) 2.3300(9), C(1)-Ge(1)-Si(4) 96.75(6), C(1)-Ge(1)-Si(1) 107.51(6), Si(4)-Ge(1)-Si(1) 86.88(2), C(21)-Si(8)-Si(4) 108.75(8), N(1)-C(1)-N(2) 104.2(17).](image2)

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$^a$ Measured at 60 °C. n.o. = not observed.
ture for both compounds, but also a higher inversion barrier for NHC-stabilized 5.

Spectroelectrochemistry

The possibility of one-electron reduction and oxidation of silylated tetrylenes and their dimerization products has been demonstrated a few times. In particular, Sekiguchi and co-workers have shown elegant examples for disilenes[35, 36] and distannenes.[37]

Real-time ESR- and UV-coupled spectroelectrochemistry can provide important information on mechanism of formation of multiple reduced and oxidized states upon electron transfer(s), on their structure, electron-density distribution, and reactivity. We therefore undertook such studies, which are thus far unprecedented for this type of compounds.[38]

The UV/Vis absorption bands of neutral digermene 2 at $\lambda = 330$ nm (7.6 x 10$^{-4}$ M$^{-1}$ cm$^{-1}$) and 470 nm (1.3 x 10$^{-4}$ M$^{-1}$ cm$^{-1}$) are almost identical to the absorptions of Kira’s isostructural disilene[39] at $\lambda = 328$ nm (8.2 x 10$^{-4}$ M$^{-1}$ cm$^{-1}$) and 469 nm (1.4 x 10$^{-4}$ M$^{-1}$ cm$^{-1}$). Compared to disilenes, digermenes are a less well investigated class of compounds. Digermerne 2, being a rather unusual bicyclic example, was thus considered an interesting opportunity for the study of some basic spectroscopic and electrochemical properties[35, 40] of this compound class. Voltamograms of 2 at a glassy carbon (GC) electrode are shown in Figure 6. The first reduction peak ($E_p = -1.835$ V) is into the vacant orbitals of 2 does not provoke its irreversible chemical transformations but it also does not cause any substantial structural reorganization either in [2]”- or in [2]” - that could be seen through the increased reorganization energy, $\lambda$, and decreased ET rate.[42]

In DME (a solvent of relatively low polarity, $\varepsilon = 7.07$, $n_0 = 1.378$),[43] the outer sphere reorganization energy, $\lambda_0$, that is, the part of total reorganization energy that is related to redistribution of the solvent molecules accompanying the transfer of one electron to 2 is quite modest and amounts to ca. 19 kJ mol$^{-1}$ in Marcus[44] or ca. 36 kJ mol$^{-1}$ in Hush[45] approximations. Since at $v = 1$ V s$^{-1}$, overall reorganization energy ($\lambda_0 + \lambda_2$) does not control ET rate yet, its rate constant, $k_i = \frac{FvD(RT)}{\lambda_0}$, where $F$ is the Faraday constant and $D$ is the diffusion coefficient,[42] is expected to be greater than 0.014 cm s$^{-1}$. With this value as a lower limit, a maximal contribution of intermolecular reorganization energy, $\lambda_2$, provoked by ET can be assessed from following equation: $k_i = Z_{1n}^e \exp(-\Delta G^*/RT)$, where $Z_{1n}$ is the heterogeneous collision frequency, for electrochemical reactions usually taken as $2 x 10^{-4}$ cm$^{-1}$.[46] $\xi$ is the transmission coefficient, assumed to be unity for an adiabatic process, and $\Delta G^*$ is the free energy of activation from $\Delta G^0$ = $(\lambda_2/4)(1 + FvD - \phi/\lambda_2)^2$, with $\lambda = \lambda_0 + \lambda_2$. Now, in order to assume $k_i > 0.014$ cm s$^{-1}$, $\lambda$ must be less than 113 kJ mol$^{-1}$, that is, $\lambda < (113 - 36)/77$ kJ mol$^{-1}$. In reality, both reduction peaks do not show any appreciable ET limitations up to $v = 10$ V s$^{-1}$, meaning that $\lambda_2$ is even smaller, $\lambda_2 < 67$ kJ mol$^{-1}$.

The oxidation of 2 is characterized by one diffusion-controlled peak (2) at $E_i = 0.315$ V), which also has electron stoichiometry of an electrochemically reversible process ($n = 1$), in spite of its somewhat large half-width, $\Delta E_{p, o/2} = 95$ mV ($v = 1$ V s$^{-1}$). When increasing the scan rate ($v > 10$ V s$^{-1}$), the cathodic branch on the voltammogram of the couple [2]+/2 starts to appear (Figure 6) but electron-transfer kinetics becomes limiting for the overall rate of oxidation, so the oxidation peak width, $\Delta E_{p, o/2}$ increases (300 mV at $v = 25$ V s$^{-1}$) with no substantial increase in the cathodic counterpart of the anodic peak.

Reversibility of ET at the first reduction step allowed us to study the anion radical species 2”- by real-time UV-spectroelectrochemistry. Corresponding cation radicals 2+ are visibly less stable: even at 250 K, it was not possible to measure their UV spectrum. During the cathodic scan from $-1.5$ V to $-1.9$ V ($v = 10$ V s$^{-1}$), the absorbance at $\lambda = 475$ nm in the UV/Vis spectrum of 2 diminishes as the potential reaches the rising part of the polarization curve to totally disappear at $E < E_i$. At the same time, the absorption of [2]”- electrogenerated at this reduction step appeared at $\lambda = 392$ nm (Figure 7).

1 Bulkeness of 2, implying that the site of ET is relatively far from the electrode so that electrode-image effects can be neglected, acts in favor of Hush reorganization energy;[40] however, ET is still supposed to be adiabatic.[36]

2 Putting aside the uncertainty in the potentials of reference electrodes and non-homogeneity of the experimental electrochemical data of heavy alkenes, one can see that their oxidation generally occurs at 0.3 - 0.5 V versus SCE, though both higher and lower values have been reported.[46, 47, 48] The published reduction potentials cover a larger span, from $-0.46$ to $-2.66$ V, probably implying that they need to be carefully revised.
The absorbance maximum at $\lambda = 475$ nm for neutral $2$ corresponds to the HOMO–LUMO $\pi(\text{Ge=Ge}) \rightarrow \pi^*(\text{Ge=Ge})$ transition (see below). Taking into account that the potentials of reversible electrochemical processes relate to the energies of the corresponding frontier orbitals (under similar experimental conditions and supposing solution free energies and working terms—the energies necessary to bring the corresponding species to the reaction zone—to be equal for both reduction and oxidation), this value (ca. 2.6 eV) is somewhat higher than the apparent electrochemical hardness of this molecule, $\Delta E = E_{p}^o - E_{red} = 2.12$ V. However, the latter value is underestimated owing to two factors: the negative kinetic shift of $E_{p}^o$ relative to $E_{p}$, which might reach several hundred mV and the fact that in spite of a large size of $2$, solvation energies for charged radicals $[2]^{-}$ and $[2]^{2-}$ are supposed to be greater than that of the neutral molecule, which diminishes both terms in the experimental $\Delta E$. For these reasons and at the given $E_{p}^o$ and $E_{red}$, the band at $\lambda = 330$ nm arises from a transition with energy higher than the HOMO–LUMO gap ($\pi(\text{Ge=Ge}) \rightarrow \pi^*(\text{Si–Si})$, according to DFT calculations).

Real-time ESR-coupled spectroelectrochemistry confirmed the paramagnetic character of the species produced by electroderection of $2$ at $E_{p}^o$. The central line in the spectrum of the radical anion ($g = 2.0272$) is accompanied by ten $^{73}$Ge satellites with $a_{G} = 22.09$ G. The spectrum has well-resolved ends, which permits as well observing the satellites from $^{29}$Si ($a_{Si} = 7.8$ G), not only on the central line but also on all low-field $^{73}$Ge satellites (Figure 8). The integration of $^{73}$Ge satellites makes up ca. 15.9 % (twofold $^{73}$Ge natural abundance, 7.8 %) indicating that the Ge–Ge linkage is not broken by the first electron uptake. The small value of the $^{73}$Ge hyperfine coupling constant ($hfcc$) $a_{G}$ in $[2]^{-}$ reflects the localization of unpaired electron mostly on the germanium $p$-type (p) orbital that has a node at the nuclei. The adjacent Si atoms are located in the nodal plane and therefore have very small spin interaction with Ge. Although Sekiguchi et al. reported very close hfcc values for $^{73}$Ge and $^{29}$Si ($a_{G} = 20$ G and $a_{Si} = 7.3$ G) for the planar ($\text{Bu}_2\text{MeSi})_2\text{Ge}$ radical, the spin in $[2]^{-}$ interacts with two Ge atoms implying that proper hfcc values are larger than the observed time-averaged values. This means that rapid exchange between spin- and charge-carrying Ge atoms of the Ge=Ge bridge (one closer to planar and another to pyramidal geometry, respectively), similar to that in the anion radical of acyclic disilene ($\text{Bu}_2\text{MeSi})_2\text{Si} \rightarrow \text{Si}(\text{Bu}_2\text{MeSi})_2\text{Si}$), might occur in $[2]^{-}$. In this species, the Ge radical center shows slight pyramidalism (even doubled, the experimental $a_{G}$ value is still smaller than those reported for pyramidal $\text{R}_2\text{Ge}$ radicals).

Upon further increasing the cathodic potential ($E_{work} = -2.0 \rightarrow -2.1$ V), the signal of $[2]^{-}$ vanished, corresponding to the transformation of this paramagnetic species into diamagnetic dianion $[2]^{2-}$. This process is chemically reversible, since returning to $E = -1.7$ V (zone of the limiting current of the oxidation of $[2]^{2-}$ back into $[2]^{-}$) made the spectrum of $[2]^{-}$ reappear, in agreement with the data of cyclic voltammetry. Similar chemical reversibility of both reduction steps on the ESR scale was also observed for thiatetragermacyclopentene and thiatetra-silacyclopentene with endocyclic $\text{M} = \text{M}$ bonds.

Kinetics of the decay of anion radicals $[2]^{2-}$ (Figure 9) corresponds to a unimolecular process. With time, the formal kinetic order becomes smaller than unity probably because of signal broadening with a concomitant decrease in the peak intensity. The $log(k)-T$ plot, obtained from temperature-dependent ESR measurements, permitted the determination of the apparent activation energy of this process, $\Delta G^\ddagger = 17.2 \pm 3.2$ kJ mol$^{-1}$ and, through the Eyring equation (supposing $kT/h \approx 8.1 \times 10^{12}$ s$^{-1}$), its activation entropy, $\Delta S^\ddagger = -189$ J mol$^{-1}$K$^{-1}$.

With the rate constant $k_{236} = 1.2 \times 10^{-3}$ s$^{-1}$, the $\Delta G^\ddagger$ value features the anion radical as a relatively stable species. Activation entropy, $\Delta S^\ddagger$, seems unusually high for a unimolecular reaction. Since large reorganization energy has not been revealed by voltammetry, this is not related to rehybridization of one Ge becoming substantially more tetrahedral relative to...
neutral 2. One possible reason for the large $\Delta S^\ddagger$ value might be a large release of steric strain energy (or twisting around the Ge–Ge bond) in the reaction, accounting for the decay of [2]$^{--}$. Another reason might be that the decay of [2]$^{--}$ starts with the population of a different electronic state of higher symmetry. Of course, overestimation of the probability factor in the Arrhenius equation would also contribute to a high $\Delta S^\ddagger$ value.

The oxidation of 2, set up in the ESR cell at the potential $+0.3 \text{ V}$, produces cation radicals, [2]$^{+}$, which are less stable than anion radicals, [2]$^{--}$ (Figure 6). The ESR signal of [2]$^{+}$ ($g = 2.0238$) could only be observed for 10 s at 245 K (central line, Figure 10). The decay of [2]$^{+}$ results in secondary Ge-centered radical species ($g = 2.0258$) that accounts for the emerging doublet-type spectrum (Figure 10). Its doublet pattern arises from the coupling with one nucleus of spin $I = 1/2$ (for example, $^1\text{H}$ or $^{19}\text{F}$) and hfcc value, $a = 19.98$ G. Though $^{73}\text{Ge}$ satellites (ten lines for $^{73}\text{Ge}$ with $I = 9/2$) of this doublet are lost in the noise, three groups of $^{29}\text{Si}$ satellites (two lines for $I = 1/2$) are well seen. Reconstruction of the spectrum ($2a_{\text{Si,ax}} = 7.95$ G) features this species as containing planar Ge with two Si(SiMe$_3$)$_2$ branches and a broken Ge–Ge bond. Two Si atoms (Si(1) and Si(1')) with $a_{\text{Si,ax}} = 7.95$ G are located in the nodal plane of the spin-carrying p$_x$(Ge) orbital (see Figure 3) so their small hfcc value is due to the interactions mostly by spin polarization. With respect to this orbital, two SiMe$_3$ groups at these $\alpha$-Si atoms are non-equivalent. The geometry of the Ge(Si(SiMe$_3$)$_2$)$_2$ fragment is such that while one Si–SiMe$_3$ $\alpha$-bond ($\beta_{\text{Si,ax}}$-Si atom) is almost parallel to p$_x$(Ge), the second one forms a substantial dihedral angle with it, $\zeta_{\text{p}_x\text{Ge-Si(SiMe}_3)_2}$ (for example, $-53.92^\circ$ in neutral 2, Figure 3). With spin interactions of $\gamma$-type orbitals being related to the cosine of this angle,$^{[58]}$ their hfcc values are assigned as $a_{\text{Si,ax}} = 13.01$ G and $a_{\text{Si,eq}} = 5.37$ G ($\beta$-Si atoms denoted as $\beta_{\text{Si,eq}}$ and $\beta_{\text{Si,ax}}$ reflecting the orientation of the corresponding $\alpha$(Si–SiMe$_3$) bonds). Atoms Si(2) and Si(2'), formally also at a $\beta$-position to Ge, have zero contribution because they are located in the plane perpendicular to the p$_x$(Ge) orbital.

Since the interaction of [2]$^{+}$ with the only possible external F-donor, the (CF$_3$)$_3$B anion, is not very likely for steric reasons (also, the hfcc value of $^{19}\text{F}$ is expected to be higher; for example, 65.21 G in Me$_2$Si(F)$_2$)$^{[56]}$ and 31.9 G in Bu$_2$MeSi(F)$^{[57]}$), the doublet pattern presumably arises from a proton at Ge, resulting from intramolecular hydride transfer in the cation radical. With time, this radical evolves, giving rise to a non-identified C-centered organic radical ($g = 2.0026$).

**Computational Study**

The results of density functional calculations were used to gain some further insights into the structure and bonding situation of the fleeting intermediates of the electrochemical processes, radical cation [2]$^{+}$, and radical anion [2]$^{--}$. The applied theoretical method$^{[56]}$ is justified by the good agreement between the experimental structural data obtained for bicyclic digermene 2 and that predicted by the computations. The calculated molecular structure of digermene 2 is, in all important details, very close to that determined by XRD. Even relatively weak modes, as for example, the trans bending or the twisting of the Ge–Ge bond are reproduced with high accuracy (trans-bent angle $\beta$: 2.5° (XRD) versus 5.8° (calcld); twist angle, $\tau$: 16.2° (XRD) versus 18.8° (calcld), see Figure 3 and 11 and the Supporting Information, Table S2, for further details). In addition, the calculated UV data for digermene 2 can be used to gauge the quality of the calculated structure. The dominating bands in the UV spectra of digermene 2 at $\lambda = 330$ nm and at $\lambda = 470$ nm are assigned to the $\pi$(Ge–Ge)---$\pi^*$(Si–Si) transition $(\lambda_1,\text{calcld}) = 337$ nm and to the $\pi$(Ge–Ge)---$\pi^*$(Ge–Ge) transition $(\lambda_2,\text{calcld}) = 485$ nm. A relative low ionization energy, IP, of digermene 2 to give corresponding radical cation [2]$^{+}$ is predicted by the computations (IP = 538 kJ mol$^{-1}$ (5.57 eV)$^{[58]}$ in agreement with a high-lying HOMO of $\pi$(Ge–Ge) character (see the Supporting Information for surface plots of the frontier orbitals of digermene 2). The removal of one electron from the $\pi$(Ge–Ge) orbital results in a significant elongation of the Ge–Ge bond (239.0 pm versus 228.4 pm in the digermene 2, ca 5% elongation). The flexible polysilane framework can, how-
ever, compensate for this pure bond elongation and the overall structure of digermene 2 is not changed significantly upon ionization (Figure 11).

The electron affinity of digermene 2 to give the corresponding radical anion is substantial ($\Delta E_a = -128$ kJ mol$^{-1}$). The structural consequences of the one-electron reduction are also remarkable: the Ge–Ge bond is markedly stretched (246.6 pm versus 228.4 pm in the digermene 2, ca. 8% elongation) and both germanium centers are significantly pyramidalized, although to a different extent (bent angle $\beta$(Ge1) = 92.5$^\circ$ and $\beta$(Ge2) = 50.1$^\circ$; see Figure 12a). The SOMO of radical anion [2]$^-$ is of $\pi^*$ symmetry and it is delocalized over both germanium atoms (see Figure S3 in the Supporting Information). Due to the non-symmetrical structure of radical anion [2]$^-$, its calculated spin density (Figure 12b) is different at both germanium atoms.

This result suggests that the observed equivalence of the two germanium atoms by ESR spectroscopy is only time averaged. The SOMO of radical anion [2]$^-$ has almost pure $\pi^*$ (Ge–Ge) character (see the Supporting Information for a surface diagram of the SOMO), with nodal planes at the germanium atoms. Therefore only small hyperfine interactions between the unpaired electron and the germanium atoms are to be expected, in qualitative agreement with the experimental observation.

The related acyclic persilylated disilene and distannene radical anions, [23]$^-$ and [24]$^-$ show charge/red radical separation in the solid state and in solution.[39,51,52] In the case of disilene radical anion [23]$^-$, an equilibrium between equivalent structures that is fast on the ESR timescale exhibits a symmetric structure at room temperature.[39]

The solid-state structures of both radical anions showed a strong twist around the E–E bond. In addition, one tetrel atom E was found significantly pyramidalized, indicating the localization of an electron lone pair at this position. The second tetrel atom showed an almost planar coordination, which is typical for persilylated tetryl radicals. The results of structure optimizations for acyclic persilylated digermeny1 radical anion [25]$^-$ predict also for this model compound radical/charge separation. The germanium center, Ge1, of radical anion [25]$^-$ is strongly pyramidalized ($\beta$(Ge1) = 88.9$^\circ$) while at the less pyramidalized germanium atom, Ge2, ($\beta$(Ge2) = 39.4$^\circ$) an extremely high spin density is predicted (Figure 12b, d). The strong twist of the molecule around the Ge1–Ge2 bond efficiently separates the radical and anion parts ($\tau = 73.9^\circ$). The comparison between the calculated structures of model radical anion [25]$^-$ and [2]$^-c$ indicates also for the latter the onset of the separation between the anion and the radical. This is shown by the strong pyramidalization of germanium atom Ge1 and by the significant higher spin density at the second atom, Ge2 (Figure 12a, c). The fused bicyclopolymerization of radical anion [2]$^-$ obviously prevents the highly twisted arrangement of Ge–Ge bond, which is needed for a complete separation and allows for a certain delocalization of the additional electron across both germanium atoms, as indicated by the calculated spin density for radical anion [2]$^-$ (Figure 12c).

Figure 11. Ball and stick representation of the computed molecular structures of digermene 2 and its radical ions; the Si($\text{Ge}^-$–Ge–Si) core is accentuated, the polysilane backbone is shown in the wireframe mode. a) [2]$^-$; important parameter of the Ge–Ge linkage: Ge1–Ge2 228.4 pm, Si–Ge1 141.4$^\circ$, Si–Ge1 141.4$^\circ$; bent angle $\beta$(Ge1) = 5.8$^\circ$, $\beta$(Ge2) = 5.8$^\circ$; twist angle $\tau$ = 188.8$^\circ$. b) [2]$^-$; Ge1–Ge2 239.0 pm, Si–Ge1 143.7$^\circ$, Si–Ge1 143.7$^\circ$; bent angle $\beta$(Ge1) = 1.9$^\circ$, $\beta$(Ge2) = 1.9$^\circ$; twist angle $\tau$ = 188.8$^\circ$. c) [2]$^-$; Ge1–Ge2 246.6 pm, Si–Ge1 118.6$^\circ$, Si–Ge1 129.3$^\circ$; bent angle $\beta$(Ge1) = 92.5$^\circ$, $\beta$(Ge2) = 50.1$^\circ$; twist angle $\tau$ = 12.5$^\circ$. Calculated at M062X/6-311+G(d,p) (Si,C,H) def2tzvp (Ge); color code: black (Ge), dark gray (Si), light gray (C), hydrogen atoms are omitted for clarity.

Figure 12. Ball and stick representation of the computed molecular structures of radical anions. a) [2]$^-$; the Si($\text{Ge}^-$–Ge–Si) core is accentuated; the polysilane backbone is shown in the wireframe mode; important parameter of the Ge–Ge linkage: Ge1–Ge2 246.6 pm, Si–Ge1 118.6$^\circ$, Si–Ge1 129.3$^\circ$; bent angle $\beta$(Ge1) = 92.5$^\circ$, $\beta$(Ge2) = 50.1$^\circ$; twist angle $\tau$ = 12.5$^\circ$. b) [25]$^-$; Ge1–Ge2 250.4 pm, Si–Ge1 90.4$^\circ$, Si–Ge1 104.6$^\circ$; bent angle $\beta$(Ge1) = 88.9$^\circ$, $\beta$(Ge2) = 39.4$^\circ$; twist angle $\tau$ = 73.9$^\circ$. Calculated at M062X/6-311+G(d,p) (Si,C,H) def2tzvp (Ge); color code: light gray (Ge), black (Si, gray (C), hydrogen atoms are omitted for clarity. c) Calculated SCF spin density (difference between $\alpha$ and $\beta$ spins) of radical anion [2]$^-$. d) Calculated SCF spin density (difference between $\alpha$ and $\beta$ spins) of radical anion [25]$^-$. Positive spin density (white), negative spin density (black), surface isodensity value 0.0008, color code: light gray (Ge), black (Si, gray (C), white (H). Calculated at B3LYP/def2tzvp/M062X/6-311+G(d,p) (Si,C,H); def2tzvp(Ge)).
Conclusion

The chemistry of silylated tetrylenes and the respective compounds containing double bonds between higher Group 14 elements has made remarkable progress in recent years. However, while a fair number of compounds of this type now exist, reactivity and properties of these compounds are still not fully understood.

The current account concentrates on the synthesis of base-stabilized disilylated germylenes and the subsequent reaction of these to give digermenes. Digermene formation is critically dependent on the stabilization of the intermediate germylene by a phosphate base. Base-adduct formation allows the use of comparably small silyl substituents. In the absence of the base under the reaction conditions, further reaction of germylene with a silanide would occur. The choice of phosphines as bases compared to N-heterocyclic carbenes is also important as phosphines can easily be removed in order to release a free germylene, which can undergo dimerization or rearrangement reactions.

Recently we reported on the formation of a five-membered germylene adduct, which after releasing the free germylene, underwent a 1,2-silyl shift to form a silagermene and subsequently dimerized by way of a [2+2] cycloaddition. The tetrasilylated bicyclic digermene 2, described in the present study, is formed from a related four-membered germylene adduct. A closer examination of the different reaction pathways revealed a much higher degree of stabilization of the four-membered germylene dimer (that is, respective digermene 11) compared to its five-membered counterpart, 14, as the decisive factor for the different behavior.

Obtained bicyclic digermene 2 was subjected to a voltammetric study, which revealed two reversible reduction waves leading to respective radical anion [2]− and further to dianion [2]2−. The formation of [2]− was further substantiated by ESR and UV spectroscopy. In contrast to the fairly stable reduction products, radical cation [2]+, formed by one-electron oxidation, was found not to be stable enough to be studied by ESR spectroscopy. As chemical one-electron oxidation of a tetrasilyldisilene by Ph3Si−B(C6F5)3 was reported to yield a stable isolable radical cation, the reason for the low stability of [2]2+ is likely its bicyclic nature. Presumably, initially formed [2]2+ decomposed by an intramolecular hydride shift reaction. This was suggested by the observed ESR spectrum, which featured a germyl radical with strong coupling to a hydrogen atom.

By means of theoretical calculations, the structure of digermene 2 and radical anion [2]− were studied and the structure and spectroscopic features of digermene 2 were found in good agreement with experimental observations. For radical anion [2]−, the onset of radical/charge separation was suggested by the computed structural parameter and by the predicted spin distribution. Structural restrictions induced by the fused bicyclic structure of digermene radical anion [2]− prevent the perfected radical/charge separation as it is reported for related disilene and distannene radical anions. Nevertheless, the computational results suggest that the electronic situation in digermene radical anion [2]− is clearly different from that of alkene radical anions with a planar C–C core and symmetrically distributed spin density.

Experimental Section

General remarks

All reactions involving air-sensitive compounds were carried out under an atmosphere of dry nitrogen or argon using either Schlenk techniques or a glove box. All solvents were dried using a column-based solvent purification system. Potassium tert-butoxide was purchased from Merck. All other chemicals were obtained from different suppliers and used without further purification. 1H (300 MHz), 13C (75.4 MHz), and 29Si (59.3 MHz) NMR spectra were recorded on a Varian INOVA 300 spectrometer. If not noted otherwise, for all samples, C6D6 was used as solvent. To compensate for the low isotopic abundance of 29Si, the INEPT pulse sequence was used for the amplification of the signal. NMR reaction-control measurements were done by analyzing aliquots, without work-up, by adding a D2O capillary to provide a lock signal.

1,5-Digermene-2,2,4,4,6,6,8,8-octakis(trimethylsilyl)bicyclo[3.3.0]octasil-9-ene (2)

A solution of GeBr2, dioxane (705 mg, 2.20 mmol) and trimethylphosphine (167 mg, 2.20 mmol) in THF (10 mL) was cooled to −60 °C and 1[21] in DME (10 mL) was added dropwise. The reaction was stirred for 3 h at −60 °C unless NMR control measurements showed complete conversion to the PMe3 adduct 3 (29Si NMR (D2O capillary): δ = −7.7 (d, J19Si = 19 Hz, SiMe3) −10.1 (d, J18Si = 15 Hz, SiMe3) −106.3 ppm (d, J12C = 18 Hz, SiC); 31P NMR (D2O capillary): δ = −19.1 ppm). After warming the reaction mixture up to −20 °C, the solvent was removed and a dark red residue remained, which was treated three times with pentane. The pentane layers were reduced to 5 mL and upon storage at −20 °C, compound 2 was obtained as orange needles (327 mg, 17%). M.p. 347 °C (dec); 1H NMR (300 MHz): δ = 0.71 (s, 12H, Me2Si), 0.40 ppm (s, 72H, Me3Si); 13C NMR (75.4 MHz): δ = −7.9 (Me3Si), 3.3 ppm (Me2Si); 29Si NMR (59.3 MHz): δ = −9.7 (Me3Si), −10.5 (Me2Si), −92.7 ppm (SiC); UV/Vis (pentane): λ1 = 330 nm (ε = 7.6 × 103 mol−1 dm3 cm−1), λ2 = 470 nm (ε = 1.3 × 104 mol−1 dm3 cm−1); elemental analysis calcd (%) for C38H26Ge2Si14: C 35.05, H 7.82; found: C 35.86, H 7.82.

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